

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1885	electrode\$1 near (indium or indium-containing or indium-oxide or indium-alloy\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/01 09:22
L2	24	1 same (ferroelectric or piezoelectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/01 09:55
L3	24	1 same (ferroelectric or piezoelectric or perovskite)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/01 09:55
L4	24	1 same (ferroelectric or piezoelectric or perovskite or pgo)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/01 09:56

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	145736	silicon near (substrate or wafer)	US-PGPUB; USPAT	OR	ON	2006/05/01 09:31
L2	17564	indium near2 (coating or layer or film or electrode)	US-PGPUB; USPAT	OR	ON	2006/05/01 09:33
L3	88897	pattern\$4 and anneal\$4	US-PGPUB; USPAT	OR	ON	2006/05/01 09:34
L4	25132	ferroelectric	US-PGPUB; USPAT	OR	ON	2006/05/01 09:34
L5	311	2 same 1	US-PGPUB; USPAT	OR	ON	2006/05/01 09:34
L6	9	3 and 4 and 5	US-PGPUB; USPAT	OR	ON	2006/05/01 09:56
L7	82	3 and 5	US-PGPUB; USPAT	OR	ON	2006/05/01 09:57
L8	201971	"427"/\$7.ccls. or "438"/\$7.ccls.	US-PGPUB; USPAT	OR	ON	2006/05/01 09:57
L9	40	7 and 8	US-PGPUB; USPAT	OR	ON	2006/05/01 09:57